# Reactivity of the Bicyclic Amido-Substituted Silicon(I) Ring Compound $\mathrm{Si}_{4}\left\{\mathrm{~N}\left(\mathrm{SiMe}_{3}\right) \mathrm{Mes}\right\}_{4}$ with FLP-Type Character 

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#### Abstract

The bicyclic amido-substituted silicon(I) ring compound $\mathrm{Si}_{4}\left\{\mathrm{~N}\left(\mathrm{SiMe}_{3}\right) \mathrm{Mes}\right\}_{4} \quad 2 \quad\left(\right.$ Mes $=$ Mesityl $\left.=2,4,6-\mathrm{Me}_{3} \mathrm{C}_{6} \mathrm{H}_{2}\right)$ features enhanced zwitterionic character and different reactivity from the analogous compound $\mathrm{Si}_{4}\left\{\mathrm{~N}\left(\mathrm{SiMe}_{3}\right) \mathrm{Dipp}\right\}_{4} 1$ (Dipp $=2,6-{ }^{-} \mathrm{Pr}_{2} \mathrm{C}_{6} \mathrm{H}_{3}$ ) due to the smaller mesityl substituents. In a reaction with the N -heterocyclic carbene $\mathrm{NHC}^{\mathrm{Me}_{4}}(1,3,4,5-$ tetramethyl-imidazol-2-ylidene), we observe adduct formation to give $\mathrm{Si}_{4}\left\{\mathrm{~N}\left(\mathrm{SiMe}_{3}\right) \mathrm{Mes}_{4} \cdot \mathrm{NHC}^{\mathrm{Me}_{4}}\right.$ (3). This adduct reacts further with the Lewis acid $\mathrm{BH}_{3}$ to yield the Lewis acid-base


complex $\mathrm{Si}_{4}\left\{\mathrm{~N}\left(\mathrm{SiMe}_{3}\right) \mathrm{MeS}_{4} \cdot \mathrm{NHC}^{\mathrm{Me}_{4}} \cdot \mathrm{BH}_{3}\right.$ (4). Coordination of $\mathrm{AlBr}_{3}$ to 2 leads to the adduct 5. Calculated proton affinities and fluoride ion affinities reveal highly Lewis basic and very weak Lewis acidic character of the low-valent silicon atoms in 1 and 2 . This is confirmed by protonation of 1 and 2 with Brookharts acid yielding 6 and 7. Reaction with diphenylacetylene only occurs at $111^{\circ} \mathrm{C}$ with 2 in toluene and is accompanied by fragmentation of 2 to afford the silacyclopropene 8 and the trisilanorbornadiene species 9 .

## Introduction

The concept of frustrated Lewis pair (FLP) chemistry has been shown to be widely used in chemistry, and the scope of the systems has been expanded from inorganic to other fields such as organic, bioinorganic chemistry and materials science. FLPs are effective in a number of unconventional stoichiometric reactions and are also able to catalyze hydrogenations. ${ }^{[1]}$ A huge number of different systems have been developed, however, homoatomic silicon-based FLP systems are still rare. One such example represents an intermolecular FLP composed of a silylene and a silyl cation A that activates dihydrogen (Figure 1). ${ }^{[2]}$
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$R=N\left(\mathrm{SiMe}_{3}\right)$ Dipp
1

$R=E M i n d$
$\mathrm{R}=\mathrm{N}\left(\mathrm{SiMe}_{3}\right) \mathrm{Dipp}$


EMind



Figure 1. Silicon-based FLP system A and four-membered silicon ring compounds 1, B-D. A similar compound to $B$ with a different substituent is missing in Figure 1. A new Figure was generated and was sent together with this document. This also affects reference 3 .

A Lewis acidic and basic site is in principle also found in some unsaturated $\mathrm{Si}_{4} \mathrm{R}_{4}$ silicon ring compounds. For instance, the EMind- and $\mathrm{N}\left(\mathrm{SiMe}_{3}\right)_{2}$-substituted silicon-based cyclobutadiene analogue $\mathbf{B}$ features a charge-separated electronic situation with alternating planar and pyramidal silicon atoms (Figure 1). ${ }^{[3]}$ Furthermore, the amido-substituted silicon(I) ring compound 1 that contains a transannular bond was found to
exhibit zwitterionic character at the two three-coordinate silicon atoms (Figure 1). ${ }^{[4]}$ The Lewis acidic and basic site in B and 1 should allow to exploit these ring systems for FLP-type chemistry. Additionally, the amidinato and amido-substituted $\mathrm{Si}_{4}$ ring compound features a planar $\mathrm{Si}_{4}$ ring D with different polarization of the trigonal planar and four-coordinate silicon atoms however with a dominating electron delocalization of $\sigma$-, $\pi$ - and non-bonding electrons. ${ }^{[5]}$

Further four-membered cyclic silicon ring compounds have attracted recent research activities because these compounds feature flexible electronic structures and interesting reactivity due to the presence of low-coordinate silicon atoms and the release of ring strain. ${ }^{[6]}$ Recent investigations of such compounds revealed that the nature of the transannular bond can be modified upon introducing sterically rigid silacyclopentane substituents at the bridge position. This resulted in the formation of another $\mathrm{Si}_{4} \mathrm{R}_{4}$ ring compound C with an inverted $\mathrm{Si}=\mathrm{Si}$ double bond (Figure 1) that can be transformed into a saturated tetrasilacyclobutane with a $\pi$-type single bond upon 1,2-di-iodination. ${ }^{[7,8]}$

## Results and Discussion

Based on the unsaturated four-membered silicon ring compound $\mathrm{Si}_{4}\left\{\mathrm{~N}\left(\mathrm{SiMe}_{3}\right) \mathrm{Dipp}_{4} 1\right.$ with zwitterionic character (Figure 1$){ }_{1}^{[4]}$ we assumed that a similar compound with less sterically demanding substituents could display enhanced reactivity because the $\mathrm{Si}_{4}$ ring is more accessible to the substrates. Therefore, we employed the amido substituent $\mathrm{N}\left(\mathrm{SiMe}_{3}\right) \mathrm{Mes}^{[9]}$ with the sterically less bulky 2,4,6-trimethylphenyl (Mes) instead


Scheme 1. Synthesis of $2\left(R=\right.$ Mesityl $\left.=2,4,6-\mathrm{Me}_{3} \mathrm{C}_{6} \mathrm{H}_{2}\right)$.


Figure 2. Molecular structure of 2 (hydrogen atoms are omitted for clarity and thermal ellipsoids are set at a $50 \%$ probability level). Selected bond lengths/Å and angles/ ${ }^{\circ}$ : Si1-Si2 2.2375(6), Si2-Si3 2.2514(6), Si3-Si4 2.3617(6), Si1-Si4 2.3560(6), Si1-Si3 2.523(5), Si2 $\cdots$. Si4 3.5633, Si1-N1 1.7267(13), Si2-N2 1.7105(13), Si3-N3 1.7221(12), Si4-N4 1.7912(13).
of the 2,6-diisopropylphenyl group. The reductive debromination of the corresponding precursor $\left\{\mathrm{N}\left(\mathrm{SiMe}_{3}\right) \mathrm{Mes}\right\} \mathrm{SiBr}_{3}$ with commercially available Mg turnings as reducing agent provided access to the orange red bicyclo[1.1.0]tetrasilatetraamide $\mathrm{Si}_{4}\{\mathrm{~N}$ $\left(\mathrm{SiMe}_{3}\right) \mathrm{Mes}_{4} 2$ in good yield of $53 \%$ with no solvent molecules in the crystal structure (Scheme 1 and Figure 2).

Using Rieke magnesium ${ }^{[10]}$ affords 2 less selectively in contrast to the reductive debromination of the tribromosilane $\left\{\mathrm{N}\left(\mathrm{SiMe}_{3}\right) \mathrm{Dipp}\right\} \mathrm{SiBr}_{3}{ }^{[11]} \mathrm{In} 2$, the Si 2 atom is trigonal planar ( $\sum \Varangle 355.8^{\circ}$ ) and Si 4 is trigonal pyramidal ( $\sum \Varangle 287.3^{\circ}$ ). For 1 , in addition to our initial investigations and similarly to 2 , we found that this compound can be crystallized from $n$-hexane with no solvent molecules in the crystal structure. In this case, the molecular structure represented in Figure 585 in the Supporting Information is very similar to that of 2 and to that calculated in the gas phase and includes a trigonal-planar Si2 atom ( $\sum \Varangle 353.13(3)^{\circ}$ ) and a trigonal pyramidal threefold-coordinated Si4 atom ( $\sum \Varangle 320.43(2)^{\circ}$ ). This molecular structure of 1 allows to directly compare 1 and 2 . The outcome from this structural comparison is, that the trigonal planar Si2 atoms have basically identical angle sums whereas the pyramidalization at Si4 in the novel bicyclic ring compound 2 increased by $32.7^{\circ}$ upon using the smaller $\mathrm{N}\left(\mathrm{SiMe}_{3}\right)$ Mes substituent. This can be traced back to the more pronounced bending of the amido substituent at Si4, that is, the more acute $\mathrm{N} 4-\mathrm{Si} 4-\mathrm{Si} 1$ and $\mathrm{N} 4-\mathrm{Si} 4-\mathrm{Si} 3$ angles in 2 (110.79(5) and $\left.111.90(5)^{\circ}\right)$ compared to those in 1 (131.28(10) and $\left.127.32(9)^{\circ}\right)$. Furthermore, the Si-Si bond lengths in 2 around the pyramidal Si4 atom are in the range of single bonds and those around the trigonal planar Si2 atom are between single and double bonds. The bridgehead bond between Si1 and Si 3 (2.523(5) $\AA$ ) is somewhat longer than that of 1 (2.418(2) Å) but still shorter than the longest observed $\mathrm{Si}-\mathrm{Si}$ bond of $2.697 \AA$ in $t \mathrm{Bu}_{3} \mathrm{Si}-\mathrm{Si}_{\mathrm{B}} \mathrm{Bu}{ }_{3} .{ }^{[12]}$ Similar to the $\mathrm{Si}-\mathrm{Si}$ bonds, the Si4-N4 bond (1.7912(13) $\AA$ ) at Si4 is longer than that at Si2 (Si2-N2 1.7105(13) Å).

Characterization of 2 with NMR spectroscopy in $\left[\mathrm{D}_{8}\right]$ toluene revealed one signal for the bridgehead $\mathrm{Si} 1 / \mathrm{Si} 3$ atoms at 85.1 ppm . For the two threefold-coordinated silicon atoms ( $\mathrm{Si} 2 /$ Si4) one very broad signal was observed at -27 ppm which is probably related to their dynamic configuration in solution similar to the case of $1 .{ }^{[4]}$ Even at 220 K no sharp signals for these two silicon atoms were obtained. Instead line broadening of all signals occurs when cooling to this temperature and the signal for Si 2 and Si 4 disappears. ${ }^{29} \mathrm{Si}$ NMR spectra at 360 K also show only one broad signal at -27.4 ppm for Si 2 and Si 4 (Figures S13). But in the ${ }^{1} \mathrm{H}$ NMR spectrum at 370 K only one set of signals for the four amido substituents starts to form (Figures S15) indicating that a second dynamic process takes place at this temperature similar to the case of $\mathbf{1}{ }^{[4]}$ To further analyze the chemical shifts of the $\mathrm{Si}_{4}$-ring in 2, we carried out solid state $\left.{ }^{29} \mathrm{Si}^{1}{ }^{1} \mathrm{H}\right\} \mathrm{CP} / \mathrm{MAS}$ NMR spectroscopy which revealed four different signals for the silicon nuclei of the bicyclic ring. They appear at 82.6 and 88.8 ppm for the two fourfoldcoordinated bridgehead Si1 and Si 3 atoms, at 58.3 ppm for the trigonal planar Si2 atom and at -118.7 ppm for the trigonal pyramidal Si4 atom (Figures S16 and S17). Although the isotropic ${ }^{29} \mathrm{Si}$ chemical shifts in the solid-state show slight
deviations from the calculated values, the ${ }^{29} \mathrm{Si}$ chemical shift anisotropies (CSAs) in terms of $\delta_{\sigma}$ (reduced anisotropy) ${ }^{[13]}$ are in good agreement with those determined for the DFT-optimized structure of 2 (Tables S1 and S10). Note that molecular dynamics, corresponding to fast-limit angular fluctuations, ${ }^{[14]}$ may influence the experimentally determined ${ }^{29}$ Si CSA parameters (recorded at ambient and higher temperatures). A clear example of such an effect can be observed for the $\mathrm{SiMe}_{3}$ groups. Here, close to axial symmetric ${ }^{29} \mathrm{Si}$ CSA tensors ( $\eta_{\mathrm{s}} \approx 0$ ) are observed experimentally due to fast rotation of $\mathrm{SiMe}_{3}$ groups around the Si-N axis. In contrast, the DFT calculations predict non-axial ${ }^{29} \mathrm{Si}$ CSA tensors as these are performed for a single orientation/conformation only. Similarly, we also expect the inner ring of Si positions in 1 and 2 to be influenced by molecular dynamics ${ }^{[4]}$ and for this reason a comparison in terms of $\delta_{\sigma}$ is better suited compared to $\eta_{\sigma}$, that is, fast-limit angular fluctuations will only lead to a gradual decrease of $\delta_{\sigma}$ whereas larger deviation for $\eta_{\sigma}$ can be expected, depending both on the specific motion. ${ }^{[14]}$ Thus, the large $\delta_{\sigma}$ for Si4 of -291.7 ppm in 2 clearly reflects the trigonal pyramidal configuration, which is in the similar range as observed for $\mathrm{Si} 2 / 4$ in $1 .{ }^{14]}$ The $\delta_{\sigma}$ values for $\mathrm{Si} 1 / \mathrm{Si} 2 / \mathrm{Si} 3$ in 2 are all in a similar range ( $\delta_{\sigma}=-100.6,-135.8$, $-95.6 \mathrm{ppm})$. For the four-coordinate $\mathrm{Si} 1 / 3$ positions, the larger $\delta_{\sigma}$ value of -100.6 and -95.6 ppm likely is a result of the partial double bond character between Si 1 and Si 2 and Si 2 and Si 3 . Compared to $1(\cdot 2.5 \mathrm{PhMe}$ ) with two different trigonal pyramidal Si atoms, the isotropic ${ }^{29} \mathrm{Si}$ chemical shifts for Si 2 and Si 4 are shifted to higher ( $\Delta \delta=74.3$ ) and lower ppm values ( $\Delta \delta=58.7$ ), respectively, indicating enhanced zwitterionic character of 2 in comparison to $\mathbf{1}(\cdot 2.5 \mathrm{PhMe})$ in the solid state.

EPR spectroscopy of 2 revealed that it is EPR silent in solution and in the solid state at room temperature. The calculated singlet triplet energy gap of 2 amounts to $\Delta E=$ $30.0 \mathrm{~kJ} \mathrm{~mol}^{-1}$. The singlet ground state of 2 and its closed shell character was confirmed with $\operatorname{CASSCF}(10,10)$ calculations ${ }^{[15]}$ that reveal $n_{\text {rad }}=12.77 \%^{[16]}$ and $Y=5.75 \%{ }^{[17]}$ and thus no diradical character for 2 (Figure S98). The electronic structure of 2 was further elucidated using DFT calculations (TPSS-D3(BJ)/def2TZVP). ${ }^{[8]]}$ The molecular orbitals of 2 indicate a complicated partly delocalized system (Figure 3 and Figure S96). However, the HOMO represents a coefficient of $\sigma$-symmetry at Si4 which represents the lone pair of electrons at this atom. In the HOMO-2 the single bond that is formed from p-orbitals at Si1 and Si3 can be identified. It includes some contribution from Si 2 and can also be considered as a three-center-two-electron bond. The HOMO-1 includes the Si-Si $\sigma$-bond framework of the $\mathrm{Si}_{4}$ ring. The LUMO exhibits coefficients of $\pi$-type symmetry at $\mathrm{Si} 1, \mathrm{Si} 2$ and Si 3 .

Mayer ${ }^{[19]}$ and Wiberg ${ }^{[20]}$ bond orders confirm the partial double bond character in the $\mathrm{Si} 1-\mathrm{Si} 2$ and $\mathrm{Si} 3-\mathrm{Si} 2$ bonds (1.11 and 1.14) and the single bond character in the Si4-Si1 and $\mathrm{Si} 4-\mathrm{Si} 3$ bonds ( 0.94 and 0.89 ). The bridgehead bond has a lower Mayer bond order of 0.64 in line with its longer distance compared to a typical $\mathrm{Si}-\mathrm{Si}$ single bond (Table S8). Calculated natural charges ${ }^{[21]}$ show that Si 2 (0.69) is more positively polarized than $\mathrm{Si} 1 / \mathrm{Si} 3(0.59 / 0.56)$ and that Si 4 ( 0.33 ) carries the least positive polarization. This is confirmed by the calculated


Figure 3. Kohn Sham molecular orbitals of 2 (TPSS-D3(BJ)/def2-TZVP; isovalue set at $\pm 0.04$ a.u.; representation of 2 similar to that in Figure 2). Figure 3 has very small pictures of the molecular orbitals and small labels. Please replace it by the new Figure 3 that was sent together with this document

Löwdin charges ${ }^{[22]}$ that even feature a slightly negative charge for Si4 ( -0.05 ) and a more positive charge for Si 2 ( 0.17 ) compared to Si 1 and Si 3 ( $0.07 / 0.04$; Table S9). The differences in natural charges of Si 2 and Si 4 calculated with the Mayer method are 0.22 for 1 and 0.60 for 2 . This demonstrates that the charge difference in 2 between Si 2 and Si 4 is significantly increased compared to 1 .

In the experimental UV-Vis spectrum of $\mathbf{2}$ an absorption at 310 nm was determined in $n$-hexane and a shoulder at 420 nm was found when using a different concentration. TD-DFT calculation of the UV-Vis spectrum in the gas phase (CAMB3LYP ${ }^{[23]}$ /def2-SVP, Figure S97) revealed the HOMO $\rightarrow$ LUMO transition to occur at 380 nm . Further excitations were found at 360 nm and correspond to HOMO-2 $\rightarrow$ LUMO and HOMO-1 $\rightarrow$ LUMO transitions.

Regarding the pronounced zwitterionic nature of 2 in the solid state we probed the reactivity of 2 using Lewis acids and Lewis bases. We started these investigations by performing a reaction of 2 with two equivalents of the N -heterocyclic carbene 1,3,4,5-tetramethyl-imidazol-2-ylidene $\left(\mathrm{NHC}^{\mathrm{Me}_{4}}\right.$ ) at room temperature. This resulted in an adduct formation affording 3 in $78 \%$ yield (Scheme 2). The sterically more encumbered 1 reacted with five equivalents of this NHC in an unexpected carbeneinduced amine elimination at $60^{\circ} \mathrm{C}$ in THF under release of $\mathrm{N}\left(\mathrm{SiMe}_{3}\right)_{2} \mathrm{Dipp}$ and formation of a silylone with an additional $\mathrm{Si}=\mathrm{N}$ group. ${ }^{[24]}$ This unusual reaction is obviously related to the


Scheme 2. Synthesis of 3 ( $\mathrm{R}=$ Mesityl).
sterically more demanding Dipp substituents. In contrast to this observation, the adduct 3 is actually the expected product from this reaction. The NHC is bound to the tetrahedrally coordinated Si 2 atom with a Si2-C25 bond length of 1.943(2) Å. This is in the reported range of NHC-coordinated silicon ring compounds. ${ }^{[25,26]}$ The Si 4 atom in 3 is less pyramidal ( $\sum \Varangle 311.6^{\circ}$ ) compared to 2 ( $\sum \Varangle 287.3^{\circ}$ ) which is noticeable by the decreased sum of the surrounding bond angles by $24.3^{\circ}$. Furthermore, the coordination of $\mathrm{NHC}^{\mathrm{Me}_{4}}$ affects the transannular bond. The $\mathrm{Si} 1-\mathrm{Si} 3$ bond length $(2.357(5) \AA$ ) in 3 (Figure 4) is $0.2 \AA$ shorter than that of 2 (2.523(5) $\AA$ ).

Multinuclear NMR spectroscopy of 3 showed that it coexists in toluene in an equilibrium with a minor component in a 4:1 ratio. The major component displays signals in the ${ }^{29}$ Si NMR spectrum very similar to those calculated for the DFT-optimized structure of 3 (page S99). Analysis of the H,H correlated ROESY spectrum showed that in the minor component the NHC migrated to one of the bridgehead silicon atoms. We suggest that the minor component has the structure $3^{\prime}$ depicted in Figure S20. Upon coordination of $\mathrm{NHC}^{\mathrm{Me}_{4}}$ to 2, the signals in the ${ }^{29}$ Si NMR spectrum of the major component mainly appear at higher field when comparing ${ }^{29} \mathrm{Si}\left\{{ }^{1} \mathrm{H}\right\} \mathrm{CP} / \mathrm{MAS}$ NMR signals with those obtained in toluene for 3 . This is demonstrated by the signals of the bridgehead Si 1 and Si 3 atoms that are up-field shifted by 62.8 ppm to a signal at $\delta=22.3 \mathrm{ppm}$. The signal for the Si 2 atom ( $\delta=-53.1 \mathrm{ppm}$ ) is even shifted by 111.4 ppm to higher field upon the addition of $\mathrm{NHC}^{\mathrm{Me}_{4}}$ to this atom. The signal for the trigonal pyramidal Si4 atom is less affected by the NHC-coordination and only shifts by 3.4 ppm to lower field to appear at $\delta=-115.3 \mathrm{ppm}$.


Figure 4. Molecular structure of 3 (hydrogen atoms are omitted for clarity, and thermal ellipsoids are set at the $50 \%$ probability level). Selected bond lengths/Å and angles/ ${ }^{\circ}$ : Si1-Si2 2.3637(5), Si2-Si3 2.3679(5), Si3-Si4 2.3299(5), Si1-Si4 2.3195(5), Si1-Si3 2.3567(5), Si2…Si4 3.717(1), Si1-N1 1.7591(13), Si2-N2 1.7914(12), Si3-N3 1.7622(12), Si4-N4 1.8002(12), Si2-C25 1.943(2).


Scheme 3. Synthesis of 4 ( $R=$ Mesityl).

The adduct 3 cleanly reacts with the $\mathrm{BH}_{3} \cdot\left(\mathrm{SMe}_{2}\right)$ complex under addition of $\mathrm{BH}_{3}$ to the trigonal pyramidal Si 4 atom to afford 4 (Scheme 3). In compound 4 (Figure 5), all silicon atoms in the butterfly-shaped four-membered ring are saturated which is reflected in the single bond character of the $\mathrm{Si}-\mathrm{Si}$ and $\mathrm{Si}-\mathrm{N}$ bonds. We note that upon coordination of $\mathrm{BH}_{3}$ to Si 4 , the bonds around Si4 are slightly shorter than those of 2. Additionally, the resonances for Si 2 and Si 4 in the ${ }^{29} \mathrm{Si}$ NMR spectrum both appear in the high-field region ( -41.4 and -79.5 ppm , respectively) due to their fourfold coordination in 4. The coordination of $\mathrm{BH}_{3}$ to Si 4 was confirmed by the high-field resonance at -32.0 ppm in the ${ }^{11} \mathrm{~B}$ NMR spectrum compared to the signal at -19.6 ppm for $\mathrm{BH}_{3} \cdot\left(\mathrm{SMe}_{2}\right)$ in $\mathrm{C}_{6} \mathrm{D}_{6}$. Furthermore, similar ${ }^{11} \mathrm{~B}$ NMR signals ( -32.9 and -36.3 ppm in $\mathrm{C}_{6} \mathrm{D}_{6}$ ) were observed in borane complexes of NHC-coordinated trisilacyclopropylidenes. ${ }^{[27]}$

Adduct formation with 2 using only a Lewis acid was achieved with $\mathrm{AlBr}_{3}$ to yield 5 (Scheme 4). Upon coordination of $\mathrm{AlBr}_{3}$ to 2 the transannular distance between Si 1 and Si 3 increases to $2.691 \AA$ and the bond lengths between $\mathrm{Si} 1-\mathrm{Si} 2$ and $\mathrm{Si} 2-\mathrm{Si} 3$ are slightly elongated to $2.247(9) \AA$ and $2.268(9) \AA$ with respect to 2, but indicate still partial $\mathrm{Si}=\mathrm{Si}$ double bond character in these bonds. The distance between Si4 and AI1 (2.490 $\AA$ ) is somewhat longer than in a normal AI-Si single bond ( $2.47 \AA$ A ; Figure 6). ${ }^{29} \mathrm{Si}$ NMR spectroscopy of 5 revealed no signal for Si4 which is probably related to quadrupolar relaxation due to coupling to the coordinated Al1 atom. According to DFT-calculated signals for 5 a resonance at -88.5 ppm is expected for this pyramidal Si 4 atom (page S100). The signals for Si 1 and Si 3 appear at 103.6 and that of Si 2 resonates at 61.6 ppm . This is in line with the calculated ${ }^{29} \mathrm{Si}$ NMR chemical shifts and suggests that an allyl-type $\pi$-electron


Figure 5. Molecular structure of 4 (hydrogen atoms are omitted for clarity, except those at B1, and thermal ellipsoids are set at the $50 \%$ probability level). Selected bond lengths/ $\AA$ and angles $/^{\circ}$ : Si1-Si2 2.3324(5), Si2-Si3 2.3728(5), Si3-Si4 2.3216(5), Si1-Si4 2.3395(5), Si1-Si3 2.4234(5), Si2‥Si4 3.638(6), Si1-N1 1.7576(12), Si2-N2 1.7870(12), Si3-N3 1.7447(12), Si4-N4 1.7741(12), Si4-B1 2.0327(16), Si2-C25 1.9322(14).


Scheme 4. Synthesis of 5 ( $\mathrm{R}=$ Mesityl).


Figure 6. Molecular structure of 5 (hydrogen atoms are omitted for clarity, and thermal ellipsoids are set at the $50 \%$ probability level). Selected bond lengths/Å and angles $/{ }^{\circ}$ : Si4-Al1 2.4899(10), Si1-Si2 2.2466(9), Si2-Si3 2.2678(9), Si3-Si4 2.3540(9), Si1-Si4 2.3690(9), Si1 $\cdots$..i3 2.691(9), Si1-N1 1.710(2), Si2-N2 1.704(2), Si3-N3 1.710(2), Si4-N4 1.755(2); Si2-Si1-Si4 94.42(3), $\mathrm{Si} 1-\mathrm{Si} 2-\mathrm{Si} 3$ 73.18(3), $\mathrm{Si} 2-\mathrm{Si} 3-\mathrm{Si} 4$ 94.28(3), $\mathrm{Si} 3-\mathrm{Si} 4-\mathrm{Si} 1$ 69.47(3).
delocalization occurs from Si 1 to Si 3 in 5 although Si 2 deviates slightly from a trigonal planar configuration (Si2: $\left.\sum \Varangle 352.19(7)^{\circ}\right)$.

To understand the properties of the Lewis acidic and Lewis basic sites of the precursor 2, we calculated proton affinities (PA) and fluoride ion affinities (FIA) according to the Christe method ${ }^{[28]}$ (TPSS-D3(BJ)/def2-TZVP) for 1 and 2 (Table 1). These investigations revealed that both compounds show a rather low FIA. The FIA in the gas phase is $181.1 \mathrm{~kJ} \mathrm{~mol}^{-1}$ for 1 and $157.6 \mathrm{~kJ} \mathrm{~mol}^{-1}$ for 2 . Treated with the conductor like screening model COSMO (with default parameters) ${ }^{[29]}$ the FIA amounts to $13.6 \mathrm{~kJ} \mathrm{~mol}^{-1}$ for 1 and $1.8 \mathrm{~kJ} \mathrm{~mol}^{-1}$ for $\mathbf{2}$. These values are lower than those of boranes such as $\mathrm{BPh}_{3}$ and in the range of $\mathrm{Si}\left(\mathrm{NH}_{2}\right)_{4}$ and thus indicate an extremely weak Lewis acidic site. ${ }^{[30]} \mathrm{By}$ contrast, the PA of both molecules in the gas phase is considerably high ( $1102.5 \mathrm{~kJ} \mathrm{~mol}^{-1}$ ) for 1 and $1103.4 \mathrm{~kJ} / \mathrm{mol}$ for 2). Applying COSMO the PAs are in the range of 1206.9 and $1207.2 \mathrm{~kJ} \mathrm{~mol}^{-1}$. These values are higher than those calculated for model N -heterocyclic silylenes ( $\sim 980 \mathrm{~kJ} / \mathrm{mol}$ ), N-heterocyclic carbenes such as $\mathrm{NHC}^{\text {Dipp2 }}$ ( $1176 \mathrm{~kJ} / \mathrm{mol}$ ) and phosphines such as $\mathrm{Ph}_{3} \mathrm{P}\left(1031 \mathrm{~kJ} \mathrm{~mol}^{-1}\right)$ and $\mathrm{Cy}_{3} \mathrm{P}\left(1072 \mathrm{~kJ} \mathrm{~mol}^{-1}\right)$ and in the range of donor-stabilized N -heterocyclic silylenes $\left(\sim 1200 \mathrm{~kJ} \mathrm{~mol}^{-1}\right) .{ }^{[31]}$ The very low Lewis acidic character of Si2 in 2 is presumably related to the partial double bond character of the $\mathrm{Si} 2-\mathrm{Si} 1$ and $\mathrm{Si} 2-\mathrm{Si} 3$ bonds and of the $\mathrm{Si} 2-\mathrm{N} 2$ bond. The latter is reflected in the slightly shorter $\mathrm{Si} 2-\mathrm{N} 2$ bond compared to all other $\mathrm{Si}-\mathrm{N}$ bonds and the higher Mayer bond order of this bond (Table S8). The partial double bond character of these bonds reduces the silyl cation character of Si2. This is confirmed by $\delta_{\sigma}$ as stated above and the isotropic chemical shift of $\delta\left({ }^{29} \mathrm{Si}\right)=58.3 \mathrm{ppm}$ of 2 in the solid state which is shifted to higher field compared to cationic threefold-coordinated silicon species. ${ }^{[32]}$ Despite the absence of significant $\pi$-electron donation from N4 at Si4, the Lewis basicity at this position exceeds

Table 1. Calculated proton affinities (PA) and fluoride ion affinities (FIA) of 1 and 2 in the gas phase and corrected with COSMO.

|  | $\mathrm{PA}_{\text {gas phase }}$ <br> $\left[\mathrm{kJol}^{-1}\right]$ | $\mathrm{PA}_{\text {solv }}$ <br> $\left[\mathrm{kJmol}^{-1}\right]$ | $\mathrm{FIA}_{\text {gas phase }}$ <br> $\left[\mathrm{k} \mathrm{mol}^{-1}\right]$ | $\mathrm{FIA}_{\text {solv }}$ <br> $\left[\mathrm{kJ} \mathrm{mol}^{-1}\right]$ |
| :--- | :--- | :--- | :--- | :--- |
| $\mathbf{1}$ | 1102.5 | 1206.9 | 181.1 | 13.6 |
| $\mathbf{2}$ | 1103.4 | 1207.2 | 157.6 | 1.8 |

that of many common main group element bases and is comparable to that of donor-stabilized silylenes. These investigations show that 2 has intramolecular frustrated Lewis pair (FLP) character although it is solely composed of the element silicon. This is in contrast to FLPs reported in the literature that mostly consist of group 13 and group 15 elements ${ }^{[33]}$ or of group 14 and group 15 elements. ${ }^{[34]}$ Moreover, with the weak Lewis acidic site and the strong Lewis basic site, $\mathbf{2}$ belongs to the rare class of so-called "inverse" frustrated Lewis pairs. ${ }^{[35]}$

To experimentally confirm the high basicity at Si4, we performed reactions of 1 and 2 with Brookharts acid [H-$\left.\left(\mathrm{OEt}_{2}\right)_{2}\right]\left[\mathrm{B}\left\{3,5-\left(\mathrm{CF}_{3}\right)_{2} \mathrm{C}_{6} \mathrm{H}\right\}_{4}\right]^{[36]}$ (Scheme 5). Both 1 and 2 selectively react with Brookharts acid to 6 and 7 in 86 and $92 \%$ yield, respectively.

In the cations of 6 and 7, as expected, addition of the proton to the pyramidal Si 4 atom occurs. Due to positional disorder in the $\mathrm{Si}_{4}$ ring in 6, only the cation in 7 is discussed here and shown in Figure 7. In the cation of 7 an elongation of the transannular distance between Si 1 and Si 3 to 2.695(9) $\AA$ takes place. Furthermore, the $\mathrm{Si} 1-\mathrm{Si} 2, \mathrm{Si} 3-\mathrm{Si} 2$ bond lengths (2.2413(10) and 2.2263(9) Å) and the Si2-N2 1.681(2) A bond are in the range between single and double bonds and indicate $\pi$-electron delocalization between Si 2 and the adjacent atoms although Si 2 is not perfectly planar ( $\sum \Varangle 352.36(2)^{\circ}$ ). Compared to 5 the bond lengths around Si 2 are somewhat shorter which can be explained by the cationic nature of 7 .

In accordance with that, the chemical shift of Si 2 in the ${ }^{29} \mathrm{Si}$ NMR spectrum at 71.7 ppm in $\mathrm{CD}_{2} \mathrm{Cl}_{2}$ is shifted by 10.1 ppm to lower field with respect to the corresponding signal of Si 2 in


Scheme 5. Synthesis of $6\left(R=\operatorname{Dipp}=2,6-i \mathrm{Pr}_{2} \mathrm{C}_{6} \mathrm{H}_{3}\right)$ and $7(\mathrm{R}=$ Mesityl).


Figure 7. Molecular structure of the cation in 7 (hydrogen atoms, except H4 and the counter-anion, are omitted for clarity, and thermal ellipsoids are set at the $50 \%$ probability level). Selected bond lengths $/ \AA \AA$ and angles $/{ }^{\circ}:$ Si1- Si 2 2.2413(10), Si2-Si3 2.2263(9), Si1-Si4 2.2997(9), Si3-Si4 2.3161(10), Si1 $\cdots \mathrm{Si} 3$ 2.695(9), Si1-N1 1.686(2), Si2-N2 1.681(2), Si3-N3 1.689(2), Si4-N4 1.714(2); $\mathrm{Si} 3-\mathrm{Si} 2-\mathrm{Si} 1$ 74.20(3), Si2-Si1-Si4 91.72(3), $\mathrm{Si} 2-\mathrm{Si} 3-\mathrm{Si} 4$ 91.67(3), $\mathrm{Si} 1-\mathrm{Si} 4-\mathrm{Si} 3$ 71.44(3).
the neutral compound 5 . The signal for Si 2 in 7 is also shifted in the downfield region compared to the dicationic cyclobutadiene species $\left[\mathrm{Si}_{4} \mathrm{~L}_{2}(: \mathrm{SiCIL})_{2}\right] 2\left[\mathrm{Zr}_{2} \mathrm{Cl}_{4} \mathrm{Cp}^{*}{ }_{2}\right]\left(\mathrm{L}=\mathrm{PhC}(\mathrm{NtBu})_{2}, \mathrm{Cp}^{*}=\right.$ $\mathrm{C}_{5} \mathrm{Me}_{5}$ ) that displays a chemical shift at 53.4 ppm in $\mathrm{CD}_{2} \mathrm{Cl}_{2}$ for the cationic silicon centers. ${ }^{[37]}$ But with respect to free arylsubstituted silylium cations (216.2-244.7 ppm in $\left.\mathrm{C}_{6} \mathrm{D}_{6}\right)^{[38]}$ the silyl cation character of 7 is low due to the partial double bond character in the $\mathrm{Si}-\mathrm{Si}$ and $\mathrm{Si}-\mathrm{N}$ bonds and the electropositive nature of the adjacent silicon atoms. Due to ${ }^{29} \mathrm{Si}$ satellites appearing in the ${ }^{1} \mathrm{H}$ NMR spectrum in $\mathrm{CD}_{2} \mathrm{Cl}_{2}$ exact assignment of the chemical shift to the core silicon atoms in 7 was possible. The fourfold-coordinated Si4 atom has a signal at -90.8 ppm with a ${ }^{1} J_{\mathrm{H}-\mathrm{Si}}$ coupling constant of 246 Hz . The adjacent Si1 and Si 3 atoms resonate at 74.4 ppm with ${ }^{2} J_{\mathrm{H}-\mathrm{Si}}$ coupling constant of 13 Hz . For Si2 a ${ }^{3} J_{\mathrm{H}-\mathrm{Si}}$ coupling constant of 53 Hz was determined. The cation in 6 displays similar ${ }^{29} \mathrm{Si}$ NMR chemical shifts and coupling constants for $\mathrm{Si} 4\left(\delta=-107.1 \mathrm{ppm},{ }^{1} J_{\mathrm{H}-\mathrm{Si}}=\right.$ $258 \mathrm{~Hz}), \mathrm{Si} 1 / \mathrm{Si} 3\left(\delta=61.5 \mathrm{ppm},{ }^{2} J_{\mathrm{H}-\mathrm{si}}=24 \mathrm{~Hz}\right.$ and $\delta=61.9 \mathrm{ppm}$, $\left.{ }^{2} J_{\mathrm{H}-\mathrm{Si}}=10 \mathrm{~Hz}\right)$ and for $\mathrm{Si} 2\left(\delta=67.3 \mathrm{ppm},{ }^{3} J_{\mathrm{H}-\mathrm{Si}}=66 \mathrm{~Hz}\right)$. The allylic character in 6 and 7 is reminiscent to that observed in a cyclotetrasilenylium cation stabilized with $\left[\mathrm{B}\left(\mathrm{C}_{6} \mathrm{~F}_{5}\right]_{4}\right]^{-}$that was obtained in a reaction of the silyl-substituted disilene $\left(\mathrm{SiMe} t \mathrm{Bu}_{2}\right)_{2} \mathrm{Si}=\mathrm{Si}\left(\mathrm{SiMe} t \mathrm{Bu}_{2}\right)_{2}$ with $\left[\mathrm{Et}_{3} \mathrm{Si}\right]\left[\mathrm{B}\left(\mathrm{C}_{6} \mathrm{~F}_{5}\right]_{4}\right]$. ${ }^{[39]}$

Furthermore, we investigated reactions of $\mathbf{2}$ with alkenes and alkynes. We note, that compound 1 did not show any reactivity with these reagents. Even when the reactions were carried out at elevated temperature compound 1 remained unchanged. In contrast, compound 2 shows the formation of an amido-substituted silacyclopropene 8 (Figure 8) upon exposure of two equiv. of diphenylacetylene to 2 in refluxing toluene. This was confirmed by a signal in the ${ }^{29} \mathrm{Si}$ NMR spectrum at -95.3 ppm which is in the expected range of silirenes. ${ }^{[40]}$ This product indicates that a fragmentation of 2 occurred at $111^{\circ} \mathrm{C}$ in toluene in the presence of the reagent. To identify the side product from this reaction, we repeated the manipulation with an excess of 10 equiv. of diphenylacetylene in toluene at $111^{\circ} \mathrm{C}$ for $18 \mathrm{~h} .{ }^{29} \mathrm{Si}$ NMR spectroscopy of the red solid residue of the reaction showed signals of 8 besides signals of an unknown
product at $7.5,-47.7$ and -67.8 ppm . Washing the red colored residue with hexane allowed to remove 8 , and compound 9 remained and can be crystallized from a saturated toluene solution to afford pale yellow crystals of 9 with a trisilanorbornadiene scaffold (Scheme 6).

We note, that a fragmentation in solution upon reactions with alkenes was also suggested for the isostructural analogue to 1 and 2, the bicyclic germanium(I) ring compound $\mathrm{Ge}_{4}\{\mathrm{~N}(t \mathrm{Bu})$ Dipp $_{4}$ that also exhibits zwitterionic character. In this case, dissociation into two amidodigermynes, $\mathrm{LGe}=\mathrm{GeL}$ ( $\mathrm{L}=\mathrm{N}(t \mathrm{Bu})$ Dipp) molecules was proposed. This was elucidated upon reactions of $\mathrm{Ge}_{4}\{\mathrm{~N}(t \mathrm{Bu}) \text { Dipp }\}_{4}$ with ethene, cyclohexa-1,3-diene and $\mathrm{CO}_{2}$ in solution that yield the corresponding cycloaddition/ insertion products of the digermyne with the respective reagent. ${ }^{[41]}$

For the formation of 8 and 9, we propose that 2 formally dissociates into a bis(amido)silylene and an amido-substituted trisilacyclopropenylidene. The former can undergo a [2+1] cycloaddition with diphenylacetylene to give 8 and the latter can react in one $[2+1]$ and one [2+2] cycloaddition to yield a housene intermediate, that probably isomerizes to a cyclopentadiene species. This was observed in a reaction of a trisilacyclopropene with diphenylacetylene by Sekiguchi ${ }^{[42]}$ and Scheschkewitz. ${ }^{[43]}$ The cyclopentadiene intermediate can undergo a [4+2] cycloaddition to afford 9 (Scheme 7).

Only a few trisilanorbornadiene species are reported in the literature so far. One is obtained upon dimerization of a transient 9,10-disila-9,10-Dewar-anthracene. ${ }^{[44]}$ A second example was synthesized from a dianionic silyl-substituted disilacy-clo-hexadiene upon reaction with $\mathrm{Me}_{2} \mathrm{SiCl}_{2}{ }^{[45]}$ In 9, the $\mathrm{Si}-\mathrm{Si}$ bond lengths $(2.334(1) \AA$ ) are in the range of single bonds ( $2.34 \AA$ ). The $C=C$ bonds have lengths that are clearly in the double bond range ( $1.34 \AA \AA$; Figure 8 ).

As expected the Si 2 atom in the silacyclopropene ring of 9 has a signal in the ${ }^{29} \mathrm{Si}$ NMR spectrum at -67.8 ppm that is more shielded than that of the other two silicon atoms $\left(\delta\left({ }^{29} \mathrm{Si}\right)=\right.$ -47.7 ppm ) in the six-membered $\mathrm{Si}_{2} \mathrm{C}_{4}$ heterocycle. We note,
A)


8



Scheme 6. A) Reaction of 2 with diphenylacetylene at $111^{\circ} \mathrm{C}$. B) Proposed formal fragmentation of $\mathbf{2}$ into a silylene and a silacyclopropenylidene.


Scheme 7. Proposed formation of 9 ( $\mathrm{R}=$ Mesityl).
that the reaction of 2 with diphenylacetylene differs greatly from that observed with FLPs where the hydrocarbon unit usually connects the Lewis acidic and basic site in the final product. We assume that the different reactivity of 2 with the alkyne is related to the release of ring strain ${ }^{[46]}$ of the highly strained bicyclic ring system which is combined with the FLPtype character of 2.

Despite the enhanced zwitterionic character in $\mathbf{2}$ no reaction with dihydrogen occurs at room temperature. When the reaction temperature was increased to $60^{\circ} \mathrm{C}$, decomposition of 2 into the bisamido substituted silylene and an unknown side product was observed. By contrast, the isostructural $\mathrm{Ge}_{4}\{\mathrm{~N}(t \mathrm{Bu})$ Dipp $_{4}$ analogue of 1 and 2 has been reported to react with $\mathrm{H}_{2}$ at $80^{\circ} \mathrm{C}$ to give a cyclic tetrahydrido-tetragermane. ${ }^{[4]]}$

## Conclusion

In summary, we have reported a new bicyclic amido-substituted silicon(I) ring compound, 2 , that features a greater difference in the polarization of the two three-coordinate silicon atoms than the analogous compound 1 with $\mathrm{N}\left(\mathrm{SiMe}_{3}\right)$ Dipp substituents. This gives $\mathbf{2}$ more pronounced zwitterionic character and results in partially different reactivity that is mainly related to the sterically less demanding $\mathrm{N}\left(\mathrm{SiMe}_{3}\right)$ Mes substituent. The Lewis acidic and basic character of 2 was probed in a subsequent reaction with $\mathrm{NHC}^{\mathrm{Me}_{4}}$ that resulted in the formation of 3. Adduct 3 serves as a donor to $\mathrm{BH}_{3}$, which supports the Lewis acid and Lewis base properties of the two threefold-coordinated silicon atoms in 2. Coordination of only one Lewis acid is possible when using $\mathrm{AlBr}_{3}$ and yields 5 . Calculated fluoride ion and proton affinities showed that 1 and 2 have an extremely weak Lewis acidic site and a strong Lewis basic site. The high basicity of 1 and 2 was confirmed upon their reaction with Brookharts acid, which resulted in 6 and 7 . Reaction of 2 with the alkyne diphenylacetylene only proceeds at elevated temperature and is accompanied by a formal fragmentation of 2 into a bis (amido)silylene and a trisilacyclopropenylidene that were both trapped by cycloaddition to afford silacyclopropene 8 and trisilanorbornadiene 9. Further derivatization of 2 with other reagents such as chalcogens and Lewis acids are currently underway in our laboratory.

## Experimental Section

General experimental procedures for the synthesis of all compounds, characterization, quantum chemical calculations and X-ray crystallography are described in the Supporting Information.

Deposition Numbers 2105467 (for 1), 2105469 (for 2), 2105470 (for 3), 2105471 (for 4), 2105472 (for 5), 2105473 (for 6), 2105477 (for 7), 2105478 (for 8) and 2105479 (for 9) contain the supplementary crystallographic data for this paper. These data are provided free of charge by the joint Cambridge Crystallographic Data Centre and Fachinformationszentrum Karlsruhe Access Structures service https://www.ccdc.cam.ac.uk/structures/.

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## Conflict of Interest

The authors declare no conflict of interest.

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